

## EX-D30X-X High Speed Photodiode Module (rev 006)

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### Description

EX-D30X-X is an InGaAs-based photodiode module, which is designed for high speed (up to 23 GHz) analog optical transmission systems. The package is hermetically sealed with a SMA compatible RF connector.

### Key features

- Wide band application, up to 23 GHz capability
- High optical power injection capability
- High breakdown voltage
- Low Noise
- Low dark current
- Hermetically sealed, SMA output
- Built-in Bias T



### Applications

- High speed fiber optical communication system
- Microwave photonics link
- High speed test and measurement and other analog application.

### Absolute Maximum Rating:

Parameter	Sym.	Condition	Rating	Unit
Storage Temperature	T <sub>s</sub>	-	-40 to +100	°C
Operating Temperature	T <sub>op</sub>	-	-40 to +85	°C
Optical Input Power	P <sub>in</sub>	unbiased	20	mW
		V <sub>B</sub> = 7.5V	30	mW
Reverse Voltage	V <sub>r</sub>	-	< 20	V
Forward Voltage	V <sub>f</sub>	-	< 0.5	V
Bending Radius		G.657.A1 compliant	>10	mm
Lead soldering temperature	T <sub>p</sub>	-	<260	°C
Lead soldering time	t <sub>p</sub>	-	<10	Sec



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## Electro-Optical Characteristics:

(Tested under  $T_c=25^\circ\text{C}$   $V_B=5\text{V}$  unless otherwise specified.)

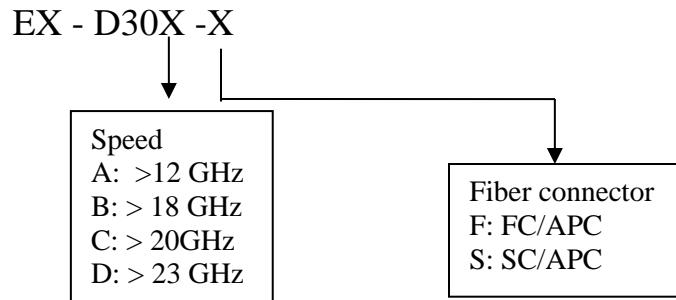
Parameter	Symbol	Condition	Min	Typ.	Max	Unit
Wavelength range	$\lambda$		1200		1650	nm
Responsivity	R	$\lambda = 1310\text{nm}$	D30A	0.80	0.85	mA/mW
			D30B&C	0.70	0.75	
			D30D	0.6	0.65	
		$\lambda = 1550\text{nm}$	D30A	0.90	0.95	
			D30B&C	0.80	0.85	
			D30D	0.65	0.75	
Dark Current	$I_d$	$V_B = 5\text{V}$	-	-	20	nA
3dB Bandwidth	BW	D30A ( $V_B=5\text{V}$ )	12	-	-	GHz
		D30B ( $V_B=5\text{V}$ )	18	-	-	GHz
		D30C ( $V_B=5\text{V}$ )	20	-	-	GHz
		D30D ( $V_B=5\text{V}$ )	22	-	-	GHz
$S_{21}$ Frequency Response Flatness <sup>1)</sup>	Ripple	1 GHz to	-	-	1	dB
	dBp-p	$(f_{3\text{dB}} - 2)$ GHz	-	-	3.5	dBp-p
Impedance	Z			50		$\Omega$
Electrical Return Loss	ERL	$V_B = 5\text{V}$	-8	-12		dB
DC Bias Voltage	$V_B$		5		7.5	V
Optical Return Loss	ORL				-40	dB
Optical Input Power <sup>2)</sup>	$P_{in}$	$V_B = 7.5\text{V}$	-	-	18	mW

1)  $S_{21}$  Frequency Response: ripple: resonant peaks/dips, dBp-p: total peak to peak  $S_{21}$  difference.

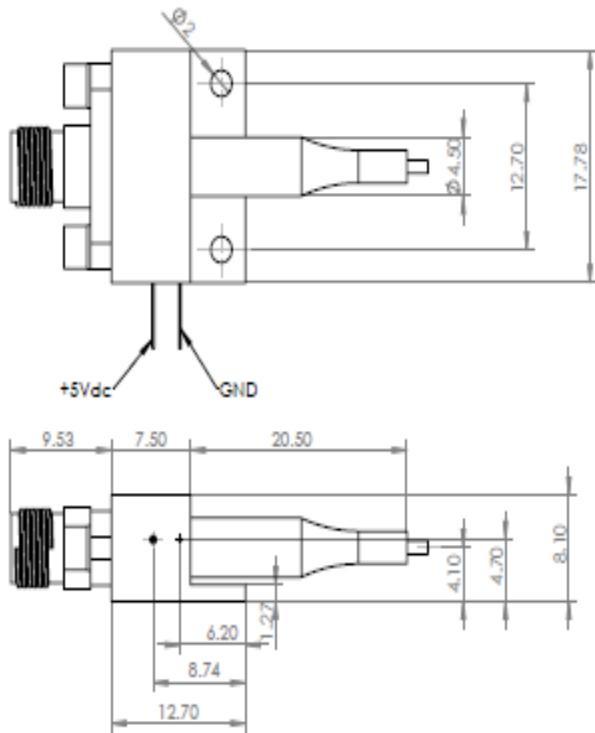
2) While the max optical input power can be higher than these spec limits if properly biased (see also the max rating table above), the spec values here are determined by unbiased conditions, given that it can be hard, in practice, to guarantee that there will be no situation where light hits the photodetector when not biased.

3) 1m long fiber length FC/APC is standard, other connectors are available upon the request

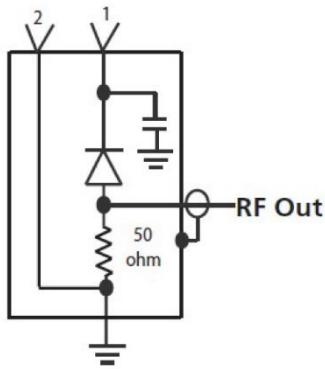
## Ordering Options:



## Outline drawing (unit: mm)



## Electrical Schematic



**Pin assignment**

Pin	Symbol	Description
1	V <sub>b</sub>	Bias Voltage for PD
2	GND	Case Ground